

# “Charge-to-spin conversion and spin-orbit torques in MBE-grown quantum materials”

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Hammond Auditorium (Engineering 120)

## Abstract

The demonstration of current-induced spin-orbit torques (SOTs) in heavy metal thin films has provided exciting new ways to harness spin-charge conversion at the device level for the next-generation magnetic-based memory technology. While the targeted material systems are prepared mainly by sputtering in SOT studies, epitaxial quantum materials have still been largely unexplored in this context. In this talk, I will present our recent research on the SOT phenomena in quantum material heterostructures grown via molecular beam epitaxy.

In the first part, I will discuss the charge-to-spin conversion in topological materials [1-3], including the topological insulator BiSb alloy and the topological semimetals. We show that the topological material heterostructures enable unique pathways to test fundamental scientific concepts, such as the bulk-boundary correspondence, in the context of spintronics. We also show that the complicated SOT phenomena in the topological semimetals depend strongly on whether the semimetals are in a pristine or naturally oxidized state.

In the second part of my talk, I will report the synthesis and characterizations of a full van der Waals epitaxial heterostructure consisting of a Dirac semimetal, ZrTe<sub>2</sub>, and a two-dimensional ferromagnet, CrTe<sub>2</sub> [4]. We observe robust ferromagnetism in CrTe<sub>2</sub> thin films down to one-unit-cell thickness. Furthermore, anomalous Hall measurements suggest the existence of chiral magnetic structures in thicker CrTe<sub>2</sub> films. Finally, we demonstrate SOT-assisted magnetization switching in the CrTe<sub>2</sub> via the current-induced spin-torques from ZrTe<sub>2</sub>.

[1] “Spin Hall conductivity in Bi<sub>1-x</sub>Sb<sub>x</sub> as an experimental test of bulk-boundary correspondence” Ou *et al*, arXiv:2311.11933.

[2] “Spin and charge interconversion in Dirac semimetal thin films”, Yanez, Ou *et al*, Physical Review Applied 16, 054031 (2021) (Editor’s Suggestion).

[3] “Giant dampinglike-torque efficiency in naturally oxidized polycrystalline TaAs thin films”, Yanez, Ou *et al*, Physical Review Applied 18, 054004 (2022) (Editor’s Suggestion).

[4] “ZrTe<sub>2</sub>/CrTe<sub>2</sub>: an epitaxial van der Waals platform for spintronics” Ou *et al*, Nature Communications 13, 2972 (2022).

## Biography

Dr. Yongxi Ou received his PhD in physics from Cornell University in 2018. After that, he joined Prof. Nitin Samarth’s group at Pennsylvania State University as a postdoctoral researcher and then became a research assistant professor in the Department of Physics. His research interests include the study of spin-orbit interactions and spin-orbit torque phenomena in heavy metal thin films deposited via sputtering technique, as well as in quantum and low dimensional material heterostructures grown via molecular beam epitaxy.